

PBSS5250X

50 V, 2 A PNP low VCEsat transistor

24 April 2023

Product data sheet

1. General description

PNP low V_{CEsat} transistor in a SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4250X

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- + High collector current capability: I_{C} and I_{CM}
- Higher efficiency leading to less heat generation
- Reduced printed-circuit board requirements
- AEC-Q101 qualified

3. Applications

- Power management
 - DC/DC converters
 - Supply line switching
 - Battery charger
 - LCD backlighting
 - Peripheral drivers
 - Driver in low supply voltage applications (e.g. lamps and LEDs).
 - Inductive load driver (e.g. relays, buzzers and motors)

4. Quick reference data

Table 1. Quid	Fable 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V	
I _C	collector current			-	-	-2	A	
h _{FE}	DC current gain	V_{CE} = -2 V; I _C = -0.1 A; T _{amb} = 25 °C		200	-	-		

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		С
2	С	collector		
3	В	base		B[
			SOT89	sym132

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PBSS5250X	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	<u>SOT89</u>			

7. Marking

Table 4. Marking codes	
Type number	Marking code[1]
PBSS5250X	%1L

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-2	А
I _{CM}	peak collector current	limited by T _{j(max)}		-	-5	А
I _B	base current			-	-0.5	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	550	mW
			[2]	-	1	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1]

Device mounted on an FR4 PCB, single-sided, 35 μ m copper, tin-plated and standard footprint. Device mounted on an FR4 PCB, single-sided, 35 μ m copper, tin-plated, mounting pad for collector 1 cm². [2]

9. Thermal characteristics

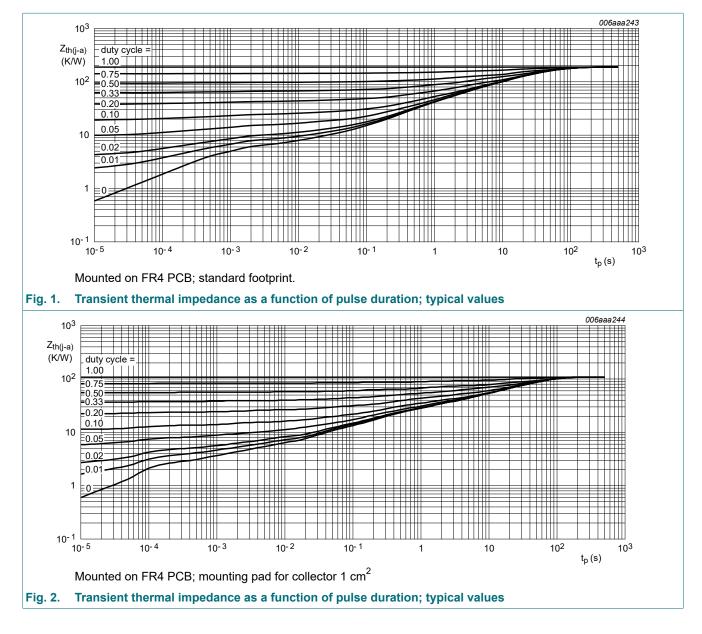
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from		[1]	-	-	225	K/W
	junction to ambient		[2]	-	-	125	K/W
			[3]	-	-	90	K/W
			[4]	-	-	80	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	16	K/W

Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint. [1]

[2] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 1 cm².

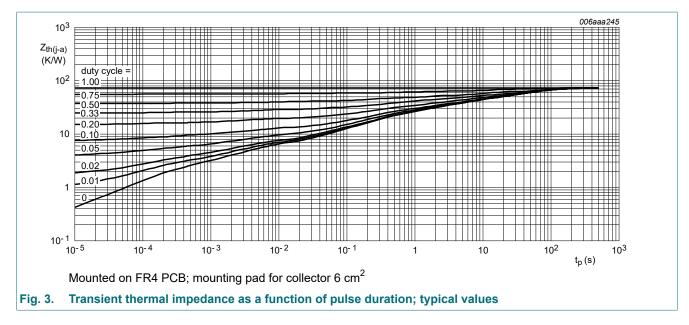
Device mounted on an FR4 PCB, single-sided, 35 μ m copper, tin-plated, mounting pad for collector 6 cm². Device mounted on a ceramic PCB, 7 cm², single-sided, 35 μ m copper, tin-plated; standard footprint. [3]

[4]



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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A; T _{amb} = 25 °C	-50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -2 mA; I _B = 0 A; T _{amb} = 25 °C	-50	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage (collector open)	I _E = -100 μA; I _C = 0 A; T _{amb} = 25 °C	-5	-	-	V
I _{CBO}	collector-base cut-off	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -50 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}; \text{ T}_{amb} = 25 ^{\circ}\text{C}$	-	-	-100	nA
I _{CES}	collector-emitter cut-off current	$V_{CE} = -50 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -2 V; I _C = -0.1 A; T _{amb} = 25 °C	200	-	-	
		V_{CE} = -2 V; I _C = -0.5 A; T _{amb} = 25 °C	200	-	-	
		V_{CE} = -2 V; I _C = -1 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	200	-	-	
		V_{CE} = -2 V; I _C = -2 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	100	-	-	
V _{CEsat}	collector-emitter	I _C = -0.5 A; I _B = -50 mA; T _{amb} = 25 °C	-	-	-90	mV
	saturation voltage	I _C = -1 A; I _B = -50 mA; T _{amb} = 25 °C	-	-	-250	mV
		I _C = -2 A; I _B = -100 mA; T _{amb} = 25 °C	-	-	-380	mV
		I_{C} = -2 A; I_{B} = -200 mA; pulsed; t_{p} ≤	-	-	-320	mV
R _{CEsat}	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	160	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_{C} = -2 \text{ A}; I_{B} = -100 \text{ mA}; T_{amb} = 25 \text{ °C}$	-	-	-1.1	V

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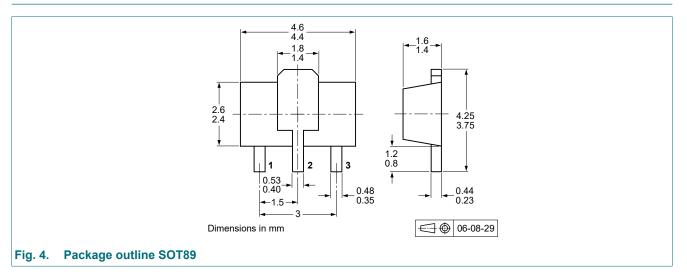
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{BEon}	base-emitter turn-on voltage	V _{CE} = -2 V; I _C = -1 A; T _{amb} = 25 °C	-1.1	-	-	V
f _T	transition frequency	V_{CE} = -5 V; I _C = -100 mA; f = 100 MHz; T _{amb} = 25 °C	100	-	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	35	pF

11. Test information

Quality information

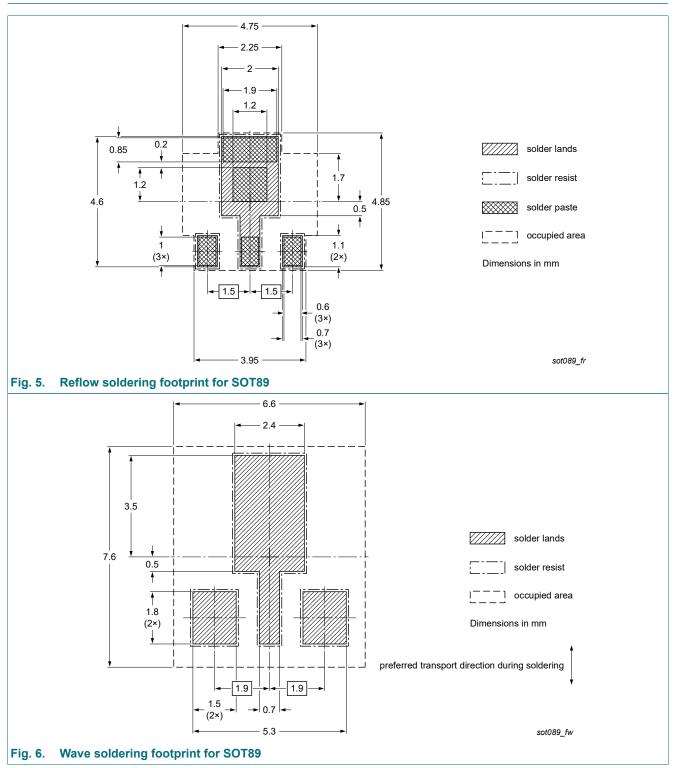
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision histo	ory						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS5250X v.3	20230424	Product data sheet	-	PBSS5250X v.2			
Modifications:	of Nexperia	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 					
PBSS5250X v.2	20041104	Product data sheet	-	PBSS5250X v.1			
PBSS5250X v.1	20030617	Product specification	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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